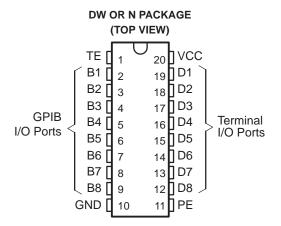
- Meets IEEE Standard 488-1978 (GPIB)
- 8-Channel Bidirectional Transceiver
- Power-Up/Power-Down Protection (Glitch Free)
- High-Speed, Low-Power Schottky Circuitry
- Low Power Dissipation . . . 72 mW Max Per Channel
- Fast Propagation Times . . . 22 ns Max
- High-Impedance pnp Inputs
- Receiver Hysteresis . . . 650 mV Typ
- Open-Collector Driver Output Option
- No Loading of Bus When Device Is Powered Down (V<sub>CC</sub> = 0)



#### description

The SN75160B 8-channel general-purpose interface bus (GPIB) transceiver is a monolithic, high-speed, low-power Schottky device designed for two-way data communications over single-ended transmission lines. It is designed to meet the requirements of IEEE Standard 488-1978. The transceiver features driver outputs that can be operated in either the passive-pullup or 3-state mode. If talk enable (TE) is high, these ports have the characteristics of passive-pullup outputs when pullup enable (PE) is low and of 3-state outputs when PE is high. Taking TE low places these ports in the high-impedance state. The driver outputs are designed to handle loads up to 48 mA of sink current.

Output glitches during power up and power down are eliminated by an internal circuit that disables both the bus and receiver outputs. The outputs do not load the bus when  $V_{CC} = 0$ . When combined with the SN75161B or SN75162B management bus transceivers, the pair provides the complete 16-wire interface for the IEEE-488 bus.

The SN75160B is characterized for operation from 0°C to 70°C.

#### **Function Tables**

EACH DRIVER										
	INPUTS									
D	TE	В								
Н	Н	Н	Н							
L	Н	Χ	L							
Н	Χ	L	z†							
Х	L	Χ	z†							

EACH RECEIVER										
INPUTS										
TE	PE	D								
L	Х	L								
L	X	Н								
Н	Х	Z								
	INPUTS	TE PE L X L X								

H = high level, L = low level, X = irrelevant, Z = high impedance

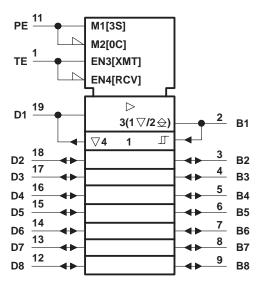


Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



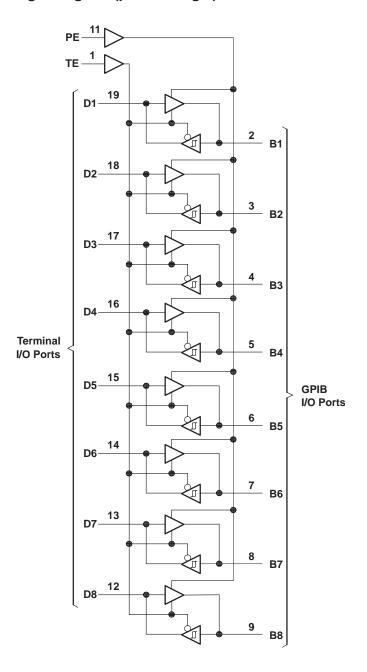
<sup>†</sup>This is the high-impedance state of a normal 3-state output modified by the internal resistors to V<sub>CC</sub> and GND.

# logic symbol<sup>†</sup>



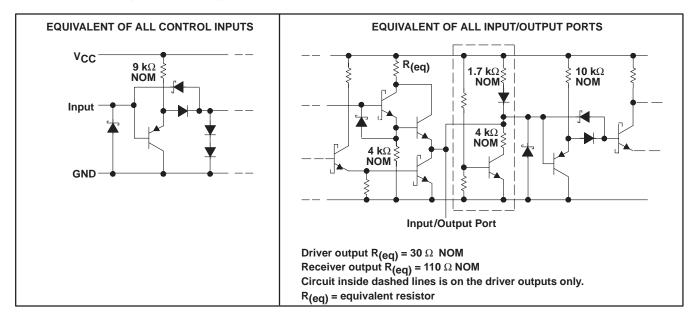
- † This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
- □ Designates 3-state outputs

# logic diagram (positive logic)





#### schematics of inputs and outputs



#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>CC</sub> (see Note 1)	
Input voltage, V <sub>I</sub>	
Low-level driver output current, I <sub>OL</sub>	100 mA
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	0°C to 70°C
Storage temperature range, T <sub>Stq</sub>	–65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. All voltage values are with respect to network ground terminal.

#### **DISSIPATION RATING TABLE**

PACKAGE	$T_{\mbox{A}} \le 25^{\circ}\mbox{C}$ POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING
DW	1125 mW	9.0 mW/°C	720 mW
N	1150 mW	9.2 mW/°C	736 mW



# SN75160B **OCTAL GENERAL-PURPOSE** INTERFACE BUS TRANSCEIVER SLLS004B - OCTOBER 1985 - REVISED MAY 1995

# recommended operating conditions

		MIN	NOM	MAX	UNIT	
Supply voltage, V <sub>CC</sub>		4.75	5	5.25	V	
High-level input voltage, V <sub>IH</sub>		2				
Low-level input voltage, V <sub>IL</sub>			V			
I Park I and a day of a comment I	Bus ports with pullups active			-5.2	mA	
High-level output current, IOH	Terminal ports			-800	μΑ	
Low-level output current, IOL	Bus ports			48	mA	
Low-level output current, IOL	Terminal ports			16	IIIA	
Operating free-air temperature, TA		0		70	°C	

# electrical characteristics over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted)

	PARAMETER		TES	MIN	TYP <sup>†</sup>	MAX	UNIT		
VIK	Input clamp voltage		I <sub>I</sub> = -18 mA	$I_I = -18 \text{ mA}$			-1.5	V	
V <sub>hys</sub>	Hysteresis voltage (V <sub>IT+</sub> - V <sub>IT-</sub> )	Bus	See Figure 8	0.4	0.65		V		
Va	High-level output voltage	Terminal	$I_{OH} = -800  \mu A$	TE at 0.8 V	2.7	3.5		V	
VOH	High-level output voltage	Bus	$I_{OH} = -5.2 \text{ mA},$	PE and TE at 2 V	2.5	3.3		V	
VOL	Low-level output voltage	Terminal	$I_{OL} = 16 \text{ mA},$	TE at 0.8 V		0.3	0.5	0.5 V	
VOL	Low-level output voltage	Bus	$I_{OL} = 48 \text{ mA},$	TE at 2 V		0.35	0.5	V	
łį	Input current at maximum input voltage	Terminal	V <sub>I</sub> = 5.5 V		0.2	100	μΑ		
I <sub>IH</sub>	High-level input current	Terminal	V <sub>I</sub> = 2.7 V	V <sub>I</sub> = 2.7 V				μΑ	
I <sub>I</sub> L	Low-level input current	Terminal	V <sub>I</sub> = 0.5 V	V <sub>I</sub> = 0.5 V			-100	μΑ	
Vivor	Voltage at bus port		Driver disabled	$I_{I(bus)} = 0$	2.5	3.0	3.7	V	
VI/O(bus)	voltage at bus port		Driver disabled	$I_{I(bus)} = -12 \text{ mA}$			-1.5		
				$V_{I(bus)} = -1.5 \text{ V to } 0.4 \text{ V}$	-1.3				
			Driver disabled	$V_{I(bus)} = 0.4 \text{ V to } 2.5 \text{ V}$	0		-3.2		
II/O(bus)	Current into bus port	Power on		V <sub>I(bus)</sub> = 2.5 V to 3.7 V			2.5 -3.2	mA	
, ,				$V_{I(bus)} = 3.7 \text{ V to 5 V}$	0		2.5		
				V <sub>I(bus)</sub> = 5 V to 5.5 V	0.7	2.5			
		Power off	$V_{CC} = 0$ ,	$V_{I(bus)} = 0 \text{ to } 2.5 \text{ V}$			-40	ŀO	
la a	Chart aircuit autaut aurrant	Terminal			-15	-35	-75	A	
los	Short-circuit output current	Bus			-25	-50	-125	mA	
loo	Supply current		No load	Receivers low and enabled		70	90	mA	
ICC	Supply current		INO IOAU	Drivers low and enabled		85	110	IIIA	
C <sub>I/O(bus)</sub>	Bus-port capacitance		$V_{CC} = 0 \text{ to 5 V},$ f = 1 MHz	$V_{I/O} = 0 \text{ to } 2 \text{ V},$		16		pF	

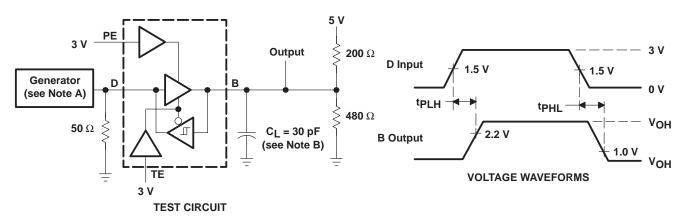
 $<sup>\</sup>dagger$  All typical values are at V<sub>CC</sub> = 5 V, T<sub>A</sub> = 25°C.



# switching characteristics, $V_{CC}$ = 5 V, $C_L$ = 15 pF, $T_A$ = 25°C (unless otherwise noted)

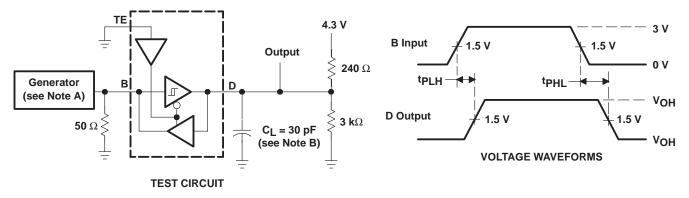
	PARAMETER	FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	MIN	TYP	MAX	UNIT	
<sup>t</sup> PLH	Propation delay time, low- to high-level output	Terminal	Bus	C <sub>L</sub> = 30 pF,		14	20	ns	
tPHL	Propagation delay time, high- to low-level output	Terminar	Dus	See Figure 1		14	20	113	
<sup>t</sup> PLH	Propagation delay time, low- to high-level output	Bus Terminal		C <sub>L</sub> = 30 pF,		10	20	ns	
<sup>t</sup> PHL	Propagation delay time, high- to low-level output	Bus	Tellillia	See Figure 2		15	22	115	
<sup>t</sup> PZH	Output enable time to high level					25	35		
<sup>t</sup> PHZ	Output disable time from high level	TE	BUS	Coo Figure 2		13	22	ns	
<sup>t</sup> PZL	Output enable time to low level	] '-	BUS	See Figure 3		22	35	] "	
tPLZ	Output disable time from low level	1				22	32		
<sup>t</sup> PZH	Output enable time to high level					20	30		
<sup>t</sup> PHZ	Output disable time from high level	TE	Townsians	Can Firmer 4		12	20		
tPZL	Output enable time to low level	] '=	Terminal	See Figure 4		23	32	ns	
tPLZ	Output disable time from low level	1				19	30		
t <sub>en</sub>	Output pullup enable time	PE	Due	Can Figure F		15	22		
<sup>t</sup> dis	Output pullup disable time	] PE	Dus	Bus See Figure 5		13	20	ns	

#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_{\Gamma} \leq$  6 ns,  $t_{f} \leq$  ns,  $Z_{O} =$  50  $\Omega$ .
  - B. C<sub>L</sub> includes probe and jig capacitance.

Figure 1. Terminal-to-Bus Test Circuit and Voltage Waveforms

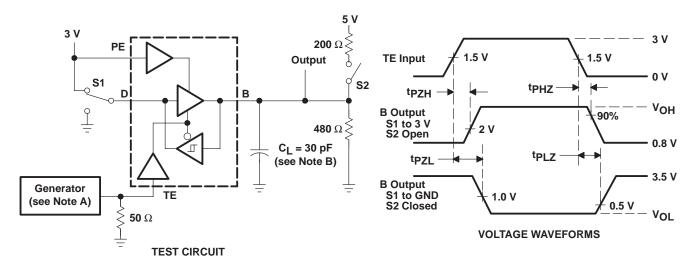


- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_{\Gamma} \leq$  6 ns,  $t_{f} \leq$  ns,  $Z_{O} = 50 \Omega$ .
  - B. C<sub>L</sub> includes probe and jig capacitance.

Figure 2. Bus-to-Terminal Test Circuit and Voltage Waveforms

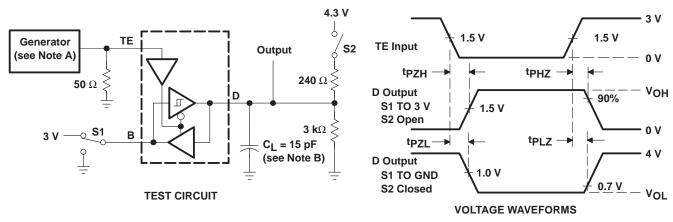


#### PARAMETER MEASUREMENT INFORMATION



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_{\Gamma} \leq$  6 ns,  $t_{\tilde{\Gamma}} \leq$  ns,  $z_{\tilde{C}} =$  50  $\Omega$ .
  - B. C<sub>L</sub> includes probe and jig capacitance.

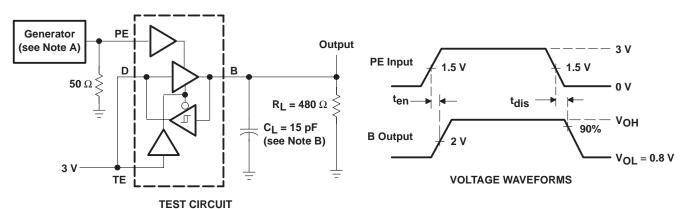
Figure 3. TE-to-Bus Test Circuit and Voltage Waveforms



- NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_{\Gamma} \leq$  6 ns,  $t_{f} \leq$  ns,  $Z_{O} = 50 \Omega$ .
  - B. CL includes probe and jig capacitance.

Figure 4. TE-to-Terminal Test Circuit and Voltage Waveforms

#### PARAMETER MEASUREMENT INFORMATION



NOTES: A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  1 MHz, 50% duty cycle,  $t_f \leq$  6 ns,  $t_f \leq$  ns,  $t_O = 50 \Omega$ .

B. CL includes probe and jig capacitance.

Figure 5. PE-to-Bus Pullup Test Circuit and Voltage Waveforms



#### TYPICAL CHARACTERISTICS

# **TERMINAL I/O PORTS HIGH-LEVEL OUTPUT VOLTAGE** vs **HIGH-LEVEL OUTPUT CURRENT** 4 $V_{CC} = 5 V$ T<sub>A</sub> = 25°C 3.5 V<sub>OH</sub> - High-Level Output Voltage - V 3 2.5 2 1.5 1 0.5 0 0 -5 -10 -15 -20 -25 -30 -35 -40 IOH - High-Level Output Current - mA

Figure 6

**TERMINAL I/O PORTS** LOW-LEVEL OUTPUT VOLTAGE **LOW-LEVEL OUTPUT CURRENT** 0.6  $V_{CC} = 5 V$ T<sub>A</sub> = 25°C V<sub>OL</sub> - Low-Level Output Voltage - V 0.5 0.4 0.3 0.2 0.1

**TERMINAL I/O PORTS OUTPUT VOLTAGE** 

0

0

10

20

30

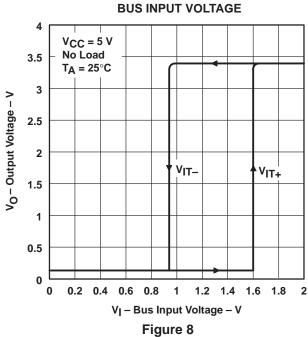
IOL - Low-Level Output Current - mA

Figure 7

40

50

60

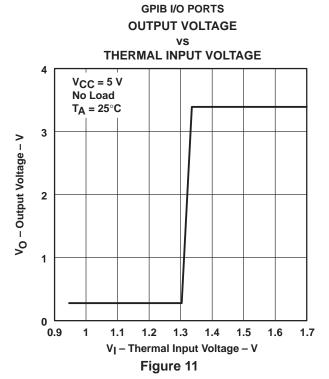




#### **TYPICAL CHARACTERISTICS**

# **GPIB I/O PORTS** HIGH-LEVEL OUTPUT VOLTAGE **HIGH-LEVEL OUTPUT CURRENT** 0 $V_{CC} = 5 V$ $T_A = 25^{\circ}C$ VOH - High-Level Output Voltage - V 3 2 0 0 -10-50-20 -40-30-60IOH - High-Level Output Current - mA

Figure 9



GPIB I/O PORTS

LOW-LEVEL OUTPUT VOLTAGE

vs

LOW-LEVEL OUTPUT CURRENT

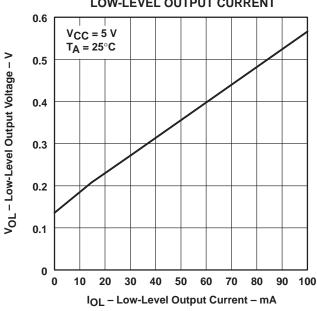
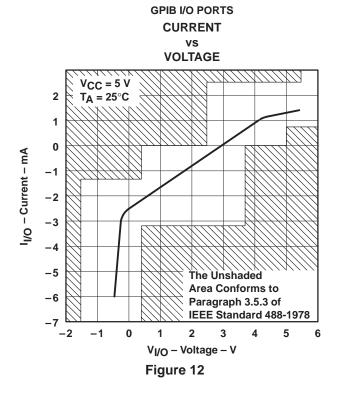


Figure 10







11-Apr-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
SN75160BDW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BDWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BDWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BDWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BDWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BDWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	SN75160B	Samples
SN75160BN	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75160BN	Samples
SN75160BNE4	ACTIVE	PDIP	N	20	20	Pb-Free (RoHS)	CU NIPDAU	N / A for Pkg Type	0 to 70	SN75160BN	Samples

 $<sup>^{(1)}</sup>$  The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between

the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.



# **PACKAGE OPTION ADDENDUM**

11-Apr-2013

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

**Important Information and Disclaimer:** The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 16-Oct-2019

# TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN75160BDWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.3	2.7	12.0	24.0	Q1

www.ti.com 16-Oct-2019



#### \*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN75160BDWR	SOIC	DW	20	2000	367.0	367.0	45.0

# N (R-PDIP-T\*\*)

# PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.





SOIC



#### NOTES:

- 1. All linear dimensions are in millimeters. Dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.

  3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not
- exceed 0.15 mm per side.
- 4. This dimension does not include interlead flash. Interlead flash shall not exceed 0.43 mm per side.
- 5. Reference JEDEC registration MS-013.



SOIC



NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SOIC



NOTES: (continued)

- 8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 9. Board assembly site may have different recommendations for stencil design.



#### IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to use these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disclaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (<a href="www.ti.com/legal/termsofsale.html">www.ti.com/legal/termsofsale.html</a>) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disclaimers for TI products.

Mailing Address: Texas Instruments, Post Office Box 655303, Dallas, Texas 75265 Copyright © 2019, Texas Instruments Incorporated